

12/22/00

ISSUE CLASSIFICATION	
Class	Subclass

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PATENT NUMBER

U.S. UTILITY Patent Application

<p>PD</p> <p>O.I.P.E.</p> <p>SCANNED SAD Q.A. WIT</p>	<p>PATENT DATE</p>
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APPLICATION NO. 09/747779	CONT/PRIOR D	CLASS 438	SUBCLASS 257 +	ART UNIT 1765 2814	EXAMINER PIENARO-CRES
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APPLICANTS

TABLE

Hong Kim

Fabrication method and structure for ferroelectric nonvolatile memory field effect transistor

PTO-2040
12/89

ISSUING CLASSIFICATION								
ORIGINAL				CROSS REFERENCE(S)				
CLASS	SUBCLASS			CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)			
INTERNATIONAL CLASSIFICATION								

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
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	_____ (Primary Examiner) (Date)			
			ISSUE FEE	
			Amount Due	Date Paid
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) (Date)		ISSUE BATCH NUMBER	
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